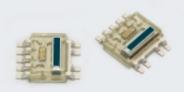


# Photo IC for laser beam synchronous detection S10317 series



• Print start timing detection for laser printers, digital copiers,

Low voltage operation (3.3 V)

S10317 series photo IC uses a high-speed PIN photodiode designed for laser beam synchronous detection. S10317 series is driven by a low voltage (3.3 V) compatible with low voltage peripheral components that will be mounted on the same PC board. Two types of current amplifiers are available with a gain of 6 times (S10317-01) and 20 times (S10317) that can be selected according to laser power to be used. Tape-and-reel shipment is also available (S10317-30 and S10317-31).

Applications

fax machines, etc.

# **Features**

- Low voltage operation (3.3 V)
- High sensitivity Current amplifier gain: 20 times (S10317) 6 times (S10317-01)

#### Active area: 2.84 × 0.5 mm Absolute maximum ratings (Ta=25 °C, unless otherwise noted) Parameter Symbol Supply voltage Vcc Power dissipation \*1 Output voltage 1 Unit V mW Output voltage \*2 Vo -0.5 to +7 V Output current lo 5 mΑ Ro terminal current RO 3 mΑ -25 to +80 °C Operating temperature Topr °C Storage temperature Tstg -40 to +85

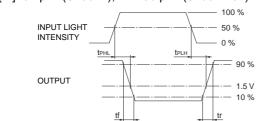
\*1: Power dissipation decreases at a rate of 4 mW/°C above Ta=25 °C.

\*2: Vcc=+0.5 V or less

# ■ Electrical and optical characteristics (Ta=25 °C, λ=780 nm, Vcc=3.3 V, Ro=5.1 kΩ, unless otherwise noted)

			(				
Parameter		Symbol	Condition	Min.	Тур.	Max.	Unit
Current consumption		lcc	No input	-	0.7	1.5	mA
High level output voltage		Vон	Iон=4 mA	2.9	-	-	V
Low level output voltage		Vol	IoL=4 mA * <sup>3</sup>	-	-	0.3	V
Threshold input power	S10317	Ртн		14	19	24	μW
	S10317-01			49.5	62	74.5	
H L propagation	S10317	<b>t</b> PHL	Pi=57 μW (S10317) Pi=186 μW (S10317-01) Duty ratio 1:1	-	130	250	ns
delay time	S10317-01			-	100	200	
L H propagation	S10317	<b>t</b> PLH		-	200	300	
delay time	S10317-01			-	150	250	
Rise time		tr	C∟=15 pF *4	-	4	7	ns
Fall time		tf		-	4	7	ns
Maximum input power		PI Max.		-	-	Ртн × 8	μW
*2. In	WAL (01001		0W. (040047.04)				

\*3: Input power [Pi]=57 μW (S10317), Pi=186 μW (S10317-01)

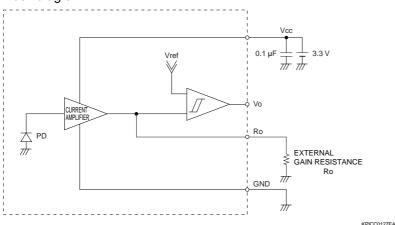




KPICC0112EA

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## Block diagram



## Function

S10317 series photo IC integrates a photodiode chip and an IC chip into the same package. The photodiode chip is internally connected to the IC chip as shown in the block diagram. S10317 series should be used with terminal Ro connected to an external gain resistance Ro.

A photocurrent is generated when a laser beam enters the photodiode. This photocurrent is fed to the input terminal of the IC and, after being amplified by the current amplifier, flows to the external gain resistance. At this time, voltages VRO at terminal Ro is com.c given by the following expression.

VRO=A × S × PI × Ro [V] .....(1)

- A: Current amplifier gain (S10317: 20 times, S10317-01: 6 times)
- S: Photodiode sensitivity [A/W] (approx. 0.44 A/W at 780 nm)
- PI: Input power [W]

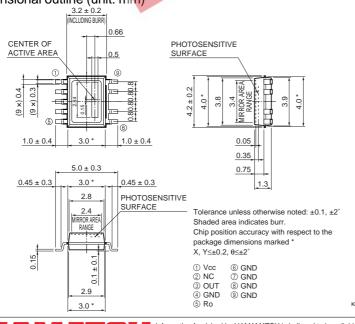
Ro: External gain resistance [ $\Omega$ ]; usable range 2 k $\Omega$  to 10 k $\Omega$ 

VRO is input to the internal comparator and compared with the internal reference voltage Vref (approx. 0.8 V) so the output Vo is "High" when VRO < Vref or "Low" when VRO > Vref.

In equatin (1), set the Ro value so that VRO is 2 to 3 V.

(Monitoring VRo shows that it is limited to about 2 V (with respect to GND) by the voltage limiting circuit. Keep this in mind when monitoring.)

# Dimensional outline (unit: mm)



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1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184, www.hamamatsu.com 1126-1 IChInO-ChO, Higdshirku, Hamamatsu Cuty, 435-8558 dapari, telephone: (o) 1 53-434-3511, Fax. (o) 1 53-434-3701, www.namatsu.com U.S.A.: Hamamatsu Corporation: 360 Foothill Road, PO.Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-128 Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany: Telephone: (49) 08152-3750, Fax: (49) 08152-2658 France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10 United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 18W, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777 North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01 Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1/E, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741